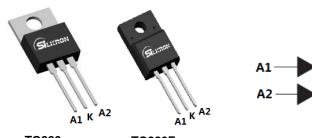


Main Product Characteristics:

IF	2×10A
VRRM	150V
T _j (max)	150 ℃
Vf(max)	0.9V



TO220 TO220F SSBD20150CT SSBD20150CTF

Schematic Diagram

Features and Benefits:

- High Junction Temperature
- High ESD Protection
- High Forward & Reverse Surge capability



Description:

Schottky Barrier Rectifier designed for high frequency switch model power supplies such as adaptors and DC/DC convertors; this product special design for high forward and reverse surge capability

Absolute Rating:

Symbol	Characterizes	Value	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage	150	V	
V _{R(RMS)}	RMS Reverse Voltage	105	V	
	Average Feminard Current	Per diode	10	Α
I _{F(AV)}	Average Forward Current	20	Α	
I _{FSM}	Non Repetitive Surge Forward Curre	180	Α	
I _{RRM}	Peak Repetitive Reverse Surge Curr	0.5	Α	
TJ	Maximum operation Junction Temper	-55~150	$^{\circ}$	
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$	

Thermal Resistance

Symbol	Characterizes	Value	Unit	
$R_{\theta JC}$	Maximum Thermal Resistance Junction To	2	℃W	
$R_{ heta JC}$	Case(per leg)	TO220F	4	°C/W

Electrical Characterizes @T_A=25℃ unless otherwise specified

Symbol	Characterizes	Min	Тур	Max	Unit	Test Condition
V_R	Reverse Breakdown Voltage	150			V	I _R =0.5mA
W	V _F Forward Voltage Drop			0.9	\/	I _F =10A, T _J =25℃
V _F				0.8	V	I _F =10A, T _J =125℃
L Jackson Current				0.1	mΛ	V _R =150V, T _J =25℃
I _R Leakage Current	Leakage Current			10	mA	V _R =150V, T _J =125℃

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I-V Curves:

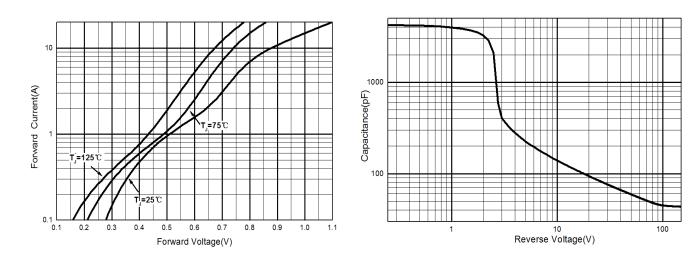


Figure 1: Typical Forward Characteristics Figure 2: Typical Capacitance Characteristics

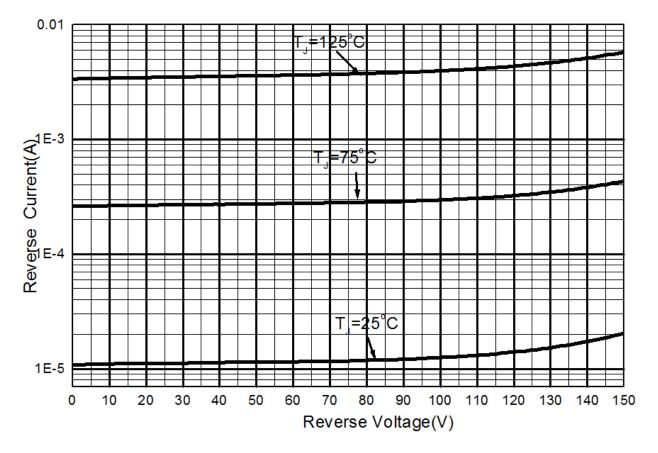
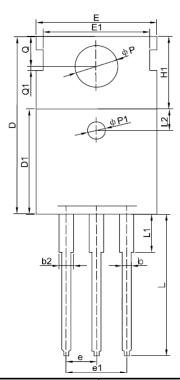


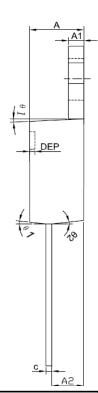
Figure 3: Typical Reverse Characteristics

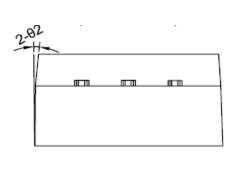




Mechanical Data: TO220:



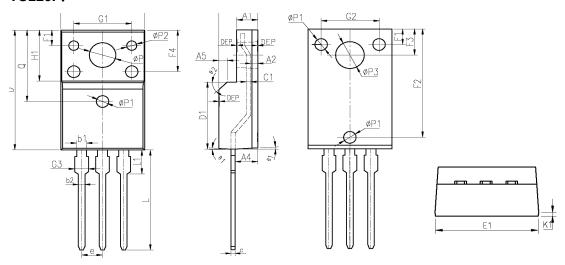




Symbol Dimension In M		nsion In Millim	Millimeters Dimension In Inc		nension In Incl	nes
Symbol	Min	Nom	Max	Min	Nom	Max
Α	4.400	4.550	4.700	0.173	0.179	0.185
A1	1.270	1.300	1.330	0.050	0.051	0.052
A2	2.590	2.690	2.790	0.102	0.106	0.110
b	0.770	-	0.900	0.030	-	0.035
b2	1.230	-	1.360	0.048	-	0.054
С	0.480	0.500	0.520	0.019	0.020	0.020
D	15.100	15.400	15.700	-	0.606	-
D1	9.000	9.100	9.200	0.354	0.358	0.362
DEP	0.050	0.285	0.520	0.002	0.011	0.020
E	10.060	10.160	10.260	0.396	0.400	0.404
E1	-	8.700	-	-	0.343	-
ФР1	1.400	1.500	1.600	0.055	0.059	0.063
e		2.54BSC			0.1BSC	
e1		5.08BSC		0.2BSC		
H1	6.100	6.300	6.500	0.240	0.248	0.256
L	12.750	12.960	13.170	0.502	0.510	0.519
L1	-	-	3.950	-	-	0.156
L2		1.85REF			0.073REF	
ФР	3.570	3.600	3.630	0.141	0.142	0.143
Q	2.730	2.800	2.870	0.107	0.110	0.113
Q1	-	0.200	-	-	0.008	-
θ1	5°	7 ⁰	90	5°	7 ⁰	90
θ2	1º	3°	5°	1º	3°	5°



TO220F:



Symbol	Dime	ension In Millim	neters	Dimension In Inches		
Symbol	Min	Nom	Max	Min	Nom	Max
Е	10.040	10.200	10.360	0.395	0.402	0.408
Α	4.500	4.700	4.900	0.177	0.185	0.193
A1	2.340	2.540	2.740	0.092	0.100	0.108
A2	0.950	1.050	1.150	0.037	0.041	0.045
A4	2.650	2.750	2.850	0.104	0.108	0.112
A5		1.00REF	-		0.039REF	
С	0.420	0.500	0.580	0.017	0.020	0.023
c1	0.420	0.500	0.580	0.017	0.020	0.023
D	15.670	15.870	16.070	0.617	0.625	0.633
Q		9.20REF	-		0.362REF	
H1		6.70REF			0.264REF	
е		2.54BSC			0.10BSC	
ΦР		3.183REF			0.125REF	
L	12.780	12.980	13.180	0.503	0.511	0.519
L1	3.250	3.450	3.650	0.128	0.136	0.144
D1		9.17REF		0.362REF		
ФР1	1.400	1.500	1.600	0.055	0.059	0.063
ФР2	1.150	1.200	1.250	0.045	0.047	0.049
ФР3		3.45REF			0.136REF	
θ1	5°	7°	9°	5°	7°	9°
θ2	-	45°	-	-	45°	-
DEP	0.050	0.100	0.150	0.002	0.004	0.006
F1	1.900	2.000	2.100	0.075	0.079	0.083
F2	13.800	13.900	14.000	0.543	0.547	0.551
F3	3.200	3.300	3.400	0.126	0.130	0.134
F4	5.300	5.400	5.500	0.209	0.213	0.217
G1	6.600	6.700	6.800	0.260	0.264	0.268
G2	6.900	7.000	7.100	0.272	0.276	0.280
G3	1.100	1.300	1.500	0.043	0.051	0.059
E1	9.900	10.000	10.100	0.390	0.394	0.398
K1	0.650	0.700	0.750	0.026	0.028	0.030
b1	1.050	1.200	1.350	0.041	0.047	0.053
b2	0.700	0.800	0.850	0.028	0.031	0.033



Ordering and Marking Information

Device Marking: SSBD20150CT&SSBD20150CTF

Package (Available) TO-220&TO220F **Operating Temperature Range** C: -55 to 150 °C

Devices per Unit

Package Type	Units/ Tube	Tubes/Inner Box	Units/Inner Box	Inner Boxes/Carton Box	Units/Ca rton Box
TO220	50	20	1000	6	6000
TO220F	50	20	1000	6	6000

Reliability Test Program

Test Item	Conditions	Duration	Sample Size
High	Tj=125℃ to 175℃ @	168 hours	3 lots x 77 devices
Temperature	80% of Max	500 hours	
Reverse	VDSS/VCES/VR	1000 hours	
Bias(HTRB)			

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